NSN 5961-01-332-8087

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-332-8087 **Overall Length:** Between 0.072 inches and 0.078 inches **Overall Height:** Between 0.030 inches and 0.040 inches **Overall Width:** Between 0.037 inches and 0.043 inches **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, instantaneous and 75.0 reverse voltage, peak **Current Rating Per Characteristic:** 75.00 milliamperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Precious Material And Location:** Eutectie die bonds surfaces terminals and land areas surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 4 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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